

IPP034N03LGHKSA1

IPP034N03LGHKSA1 Information

	Part Number	IPP034N03LGHKSA1	
-	Manufacturer	Infineon Technologies	
www.heiseper.com	Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single	
	Description	MOSFET N-CH 30V 80A TO-220-3	. 1 P
112	Package	TO-220-3	- 6°2
		For the pricing/inventory/lead time, please contact us	
For Reference Only		Website: https://www.heisener.com E-mail: salesdept@heisener.com	Reque



Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



est a Quote

IPP034N03LGHKSA1 Specifications

Manufacturer Part Number	IPP034N03LGHKSA1
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	ТО-220-3
Series	OptiMOS?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	30V
Current - Continuous Drain (Id) @ 25°C	80A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	4.5V, 10V
Vgs(th) (Max) @ Id	2.2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	25nC @ 4.5V
Input Capacitance (Ciss) (Max) @ Vds	5300pF @ 15V
Vgs (Max)	$\pm 20\mathrm{V}$
FET Feature	-
Power Dissipation (Max)	94W (Tc)
Rds On (Max) @ Id, Vgs	3.4 mOhm @ 30A, 10V
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	PG-TO220-3-1
Package / Case	ТО-220-3
	Report errors?

IPP034N03LGHKSA1 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

IPP034N03LGHKSA1 Payment Methods



If you have any question about IPP034N03LGHKSA1, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com